

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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TECHNICAL DATA SHEET

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http://www.microsemi.com

N-CHANNEL J-FET

Equivalent To MIL-PRF-19500/385

DEVICES

2N4856 2N4858 2N4860 2N4857 2N4859 2N4861 LEVELS

MQ = JAN Equivalent

MX = JANTX Equivalent

MV = JANTXV Equivalent

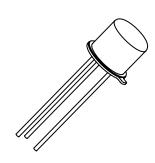
ABSOLUTE MAXIMUM RATINGS (T_C = +25°C unless otherwise noted)

Parameters / Test Conditions	Symbol	2N4856 2N4857 2N4858	2N4859 2N4860 2N4861	Unit
Gate-Source Voltage	V_{GS}	-40	-30	V
Drain-Source Voltage	V_{DS}	40	30	V
Drain-Gate Voltage	V_{DG}	40 30		V
Gate Current	I_{G}	50		mA
Power Dissipation $T_A = +25^{\circ}C^{(1)}$ $T_C = +25^{\circ}C^{(2)}$	P_{T}	0.36 1.8		W W
Operating Junction & Storage Temperature Range	T_j , T_{stg}	-65 to + 200		°C

- (1) Derate linearly 2.06 mW/°C for $T_A > +25$ °C.
- (2) Derate linearly 10.3 mW/°C for $T_C > +25$ °C.

ELECTRICAL CHARACTERISTICS ($T_A = +25$ °C, unless otherwise noted)

Parameters / Test Conditions		Symbol	Min.	Max.	Unit
$\label{eq:VDS} \begin{aligned} & \text{Gate-Source Breakdown Voltage} \\ & V_{DS} = 0, \ I_G = -1.0 \mu A \ dc \\ & & 2N4856, \ 2N4857, \ 2N4858 \\ & & 2N4859, \ 2N4860, \ 2N4861 \end{aligned}$		V _{(BR)GSS}	-40 -30		Vdc
		$V_{\mathrm{GS(off)}}$	-4.0 -2.0 -0.8	-10 -6.0 -4.0	Vdc
		I_{GSS}		-0.25 -0.25	ηА
Drain Current Cutoff $V_{GS} = -10V \text{ dc}, V_{DS} = 15V \text{ dc}$		$I_{D(off)}$		0.25	ηΑ
Drain Current Zero Gate Voltage V _{GS} = 0, V _{DS} = 15V dc 2N4856, 2N4859 2N4857, 2N4860 2N4858, 2N4861		$I_{ m DSS}$	50 20 8.0	175 100 80	mA
$\begin{aligned} & \text{Drain-Source "On" State Voltage} \\ & V_{GS} = 0, \ I_D = 20\text{mA dc} & 2\text{N4856, 2N4859} \\ & V_{GS} = 0, \ I_D = 10\text{mA dc} & 2\text{N4857, 2N4860} \\ & V_{GS} = 0, \ I_D = 5.0\text{mA dc} & 2\text{N4858, 2N4861} \end{aligned}$		V _{DS(on)}		0.75 0.50 0.50	Vdc
		r _{ds(on)}		25 40 60	Ω



TO-18 (TO-206AA)

T4-LDS-0002 Rev. 2 (090603)



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DYNAMIC CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Small-Signal, Common Short-Circuit Reverse Transfer Capacitance $\begin{aligned} V_{GS} = -10 V \ dc, \ V_{DS} = 0, \ f = 1.0 MHz \\ C_1 = 0.1 \mu F, \ L_1 = L_2 \geq 500 \mu H \end{aligned}$	C _{rss}		8.0	pF
Small-Signal, Common-Source Short-Circuit Input Capacitance $V_{GS} = -10V \; dc, \; V_{DS} = 0, \; f = 1.0 MHz$ $C_1 = 0.1 \mu F, \; C_2 = 20.1 \mu F$ $L_1 = L_2 \geq 500 \mu H$	C _{iss}		18	pF

SWITCHING CHARACTERISTICS

Parameters / Test Condit	ions		Symbol	Min.	Max.	Unit
Turn-On Delay Time	2N4856, 2N4859 2N4857, 2N4860 2N4858, 2N4861		$t_{d(on)}$		6 6 10	ηs
Rise Time	2N4856, 2N4859 2N4857, 2N4860 2N4858, 2N4861	See Figure 3 of MIL-PRF-19500/385	t _r		3 4 10	ηs
Turn-Off Delay Time	2N4856, 2N4859 2N4857, 2N4860 2N4858, 2N4861		$t_{ m d(off)}$		25 50 100	ηs

T4-LDS-0002 Rev. 2 (090603)